

ORDERING INFORMATION	ORDERING INFORMATION					
Temp. Range	Package	Part Number				
- 55 °C to 125 °C	16 nin CarDID	DG201BAK				
- 55 C to 125 C	16-pin CerDIP	DG202BAK				
	16-pin Plastic DIP	DG201BDJ DG201BDJ-E3				
	10-piii Flasiic DiF	DG202BDJ DG202BDJ-E3				
	16-pin narrow SOIC	DG201BDY DG201BDY-E3 DG201BDY-T1 DG201BDY-T1-E3				
- 40 °C to 85 °C	To pirritation doto	DG202BDY DG202BDY-E3 DG202BDY-T1 DG202BDY-T1-E3				
	16 nin TSSOD	DG201BDQ DG201BDQ-E3 DG201BDQ-T1 DG201BDQ-T1-E3				
	16-pin TSSOP	DG202BDQ DG202BDQ-E3 DG202BDQ-T1 DG202BDQ-T1-E3				

ABSOLUTE MAXIMUM RATINGS						
Parameter		Limit	Unit			
Voltages Referenced, V+ to V-		44				
GND		25	V			
Digital Inputs <sup>a</sup> , V <sub>S</sub> , V <sub>D</sub>		(V-) - 2 to (V+) + 2 or 30 mA, whichever occurs first	] v			
Current (Any terminal)		30	m A			
Peak Current S or D (Pulsed at 1 ms, 10 % duty cycle max.)		100	- mA			
Ctorogo Tomorovaturo	(AK, DK suffix)	- 65 to 150	°C			
Storage Temperature	(DJ, DY, DQ suffix)	- 65 to 125				
	16-pin plastic DIP <sup>c</sup>	470				
Power Dissipation (Pagkaga)b	16-pin narrow SOIC and TSSOP <sup>d</sup>	640	m2\A/			
Power Dissipation (Package) <sup>b</sup>	16-pin CerDIP <sup>e</sup>	900	mW			
	LCC-20 <sup>f</sup>	750				

- a. Signals on  $S_X$ ,  $D_X$ , or  $IN_X$  exceeding V+ or V- will be clamped by internal diodes. Limit forward diode current to maximum current ratings.
- b. All leads welded or soldered to PC board.
- c. Derate 6.5 mW/°C above 75 °C.
- d. Derate 7.6 mW/°C above 75 °C.
- e. Derate 12 mW/°C above 75 °C.
- f. Derate 10 mW/°C above 75 °C.



### **SCHEMATIC DIAGRAM** (typical channel)

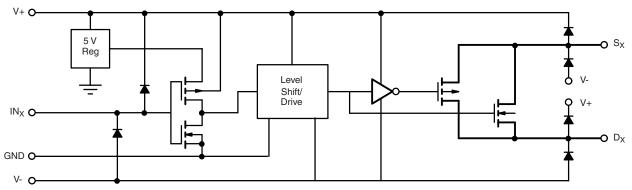


Figure 1.

SPECIFICATIONS	a								
		Test Conditions			A Suffix		_	uffix	
		Unless Specified			- 55 °C t	o 125 °C	- 40 °C	to 85 °C	
Parameter	Symbol	V+ = 15 V, V- = -15 V $V_{IN} = 2.4 V, 0.8 V^f$	Temp.b	Typ. <sup>c</sup>	Min. <sup>d</sup>	Max. <sup>d</sup>	Min. <sup>d</sup>	Max. <sup>d</sup>	Un
Analog Switch	cyzc.	V   Q = 2.1 V, 0.0 V	Tompi	.,,,,,		maxi		maxi	<u> </u>
Analog Signal Range <sup>e</sup>	V <sub>ANALOG</sub>		Full		- 15	15	- 15	15	V
Drain-Source			Room	45		85		85	
On-Resistance	R <sub>DS(on)</sub>	$V_D = \pm 10 \text{ V}, I_S = 1 \text{ mA}$	Full			100		100	Ω
R <sub>DS(on)</sub> Match	$\Delta R_{DS(on}$	5	Room	2					
Source Off Leakage		$V_S = \pm 14 \text{ V}, V_D = \pm 14 \text{ V}$	Room	± 0.01	- 0.5	0.5	- 0.5	0.5	
Current	I <sub>S(off)</sub>	V <sub>S</sub> = ± 14 V, V <sub>D</sub> = ± 14 V	Full		- 20	20	- 5	5	
Drain Off Leakage	I <sub>D(off)</sub>	$V_D = \pm 14 \text{ V}, V_S = \pm 14 \text{ V}$	Room	± 0.01	- 0.5	0.5	- 0.5	0.5	n.
Current	D(OII)		Full	. 0.00	- 20	20	- 5	5	ļ
Drain On Leakage Current	$I_{D(on)}$	$V_{S} = V_{D} = \pm 14 \text{ V}$	Room Full	± 0.02	- 0.5 - 40	0.5 40	- 0.5 - 10	0.5 10	
Digital Control									
Input Voltage High	V <sub>INH</sub>		Full		2.4		2.4		٦.
Input Voltage Low	V <sub>INL</sub>		Full			0.8		0.8	١
Input Current	I <sub>INH</sub> or I <sub>INL</sub>	V <sub>INH</sub> or V <sub>INL</sub>	Full		- 1	1	- 1	1	μ
Input Capacitance	C <sub>IN</sub>		Room	5					р
Dynamic Characteristics	<u> </u>		L			l	l	l	
Turn-On Time	tau		Room	120		300		300	
Turri-Ori Time	t <sub>ON</sub>	$V_S = 2 V$	Full						n
Turn-Off Time	t <sub>OFF</sub>	see switching time test circuit	Room	65		200		200	ns
	011	$C_L = 1000 \text{ pF, } V_q = 0 \text{ V}$	Full						
Charge Injection	Q	$R_q = 0 \Omega$	Room	1					р
Source-Off Capacitance	C <sub>S(off)</sub>	Ÿ	Room	5					
Drain-Off Capacitance	C <sub>D(off)</sub>	$V_S = 0 V$ , $f = 1 MHz$	Room	5					р
Channel On Capacitance	C <sub>D(on)</sub>	$V_{D} = V_{S} = 0 \text{ V, f} = 1 \text{ MHz}$	Room	16					1
Off Isolation	OIRR		Room	90					
Channel-to-Channel		$C_L = 15 \text{ pF, } R_L = 50 \Omega$ $V_S = 1 V_{BMS}, f = 100 \text{ kHz}$	Dears	95					d
Crosstalk	X <sub>TALK</sub>	VS = 1 VRMS, 1 = 100 KHZ	Room	95					
Power Supply				1					
Positive Supply Current	l+		Room Full			50 100		50 100	
		V <sub>IN</sub> = 0 or 5 V	Room		- 1	100	- 1	100	μΑ
Negative Supply Current	l-		Full		- 1 - 5		- 5		
Power Supply Range for	V					. 00		. 00	\
Continuous Operation	V <sub>OP</sub>		Full		± 4.5	± 22	± 4.5	± 22	\

## DG201B, DG202B

## Vishay Siliconix



SPECIFICATIONS	(for Sing	e Supply) <sup>a</sup>							
		Test Conditions Unless Specified			<b>A Suffix</b> - 55 °C to 125 °C		<b>D Suffix</b> - 40 °C to 85 °C		
Parameter	Symbol	V+ = 12 V, V- = 0 V $V_{IN} = 2.4 V, 0.8 V^f$	Temp.b	Typ. <sup>c</sup>	Min. <sup>d</sup>	Max. <sup>d</sup>	Min.d	Max. <sup>d</sup>	Unit
Analog Switch									
Analog Signal Range <sup>e</sup>	V <sub>ANALOG</sub>		Full		0	12	0	12	V
Drain-Source On-Resistance	R <sub>DS(on)</sub>	V <sub>D</sub> = 3 V, 8 V, I <sub>S</sub> = 1 mA	Room Full	90		160 200		160 200	Ω
Dynamic Characteristics	<b>3</b>					I.	ı		
Turn-On Time	t <sub>ON</sub>	V <sub>S</sub> = 8 V	Room	120		300		300	no
Turn-Off Time	t <sub>OFF</sub>	see switching time test circuit	Room	60		200		200	ns
Charge Injection	Q	$C_L = 1 \text{ nF, } V_{gen} = 6 \text{ V}$ $R_{gen} = 0 \Omega$	Room	4					рС
Power Supply									
Positive Supply Current	l+	V 0 or 5 V	Room Full			50 100		50 100	
Negative Supply Current	l-	$V_{IN} = 0 \text{ or } 5 \text{ V}$	Room Full		- 1 - 5		- 1 - 5		μΑ
Power Supply Range for Continuous Operation	V <sub>OP</sub>		Full		+ 4.5	+ 25	+ 4.5	+ 25	V

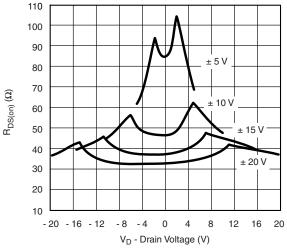
#### Notes:

- a. Refer to PROCESS OPTION FLOWCHART.
- b. Room = 25 °C, Full = as determined by the operating temperature suffix.
- c. Typical values are for DESIGN AID ONLY, not guaranteed nor subject to production testing.
- d. The algebraic convention whereby the most negative value is a minimum and the most positive a maximum, is used in this data sheet.
- e. Guaranteed by design, not subject to production test.
- f.  $V_{IN}$  = input voltage to perform proper function.

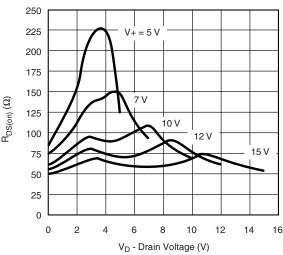
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.



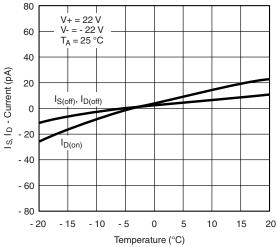
#### TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



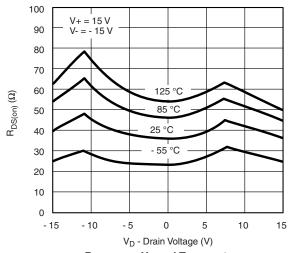
R<sub>DS(on)</sub> vs. V<sub>D</sub> and Power Supply Voltages



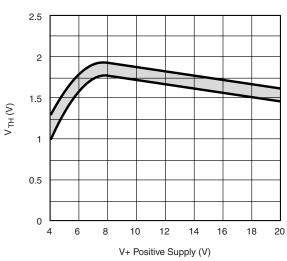
 $R_{DS(on)}$  vs.  $V_D$  and Single Power Supply Voltages



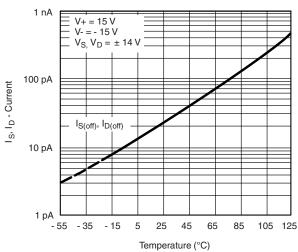
Leakage Currents vs. Analog Voltage



R<sub>DS(on)</sub> vs. V<sub>D</sub> and Temperature

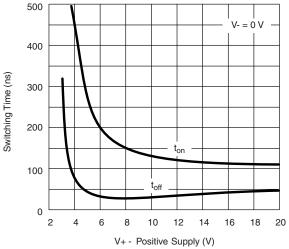


Input Switching Threshold vs. Supply Voltage

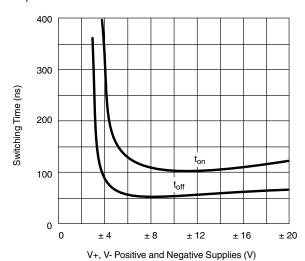


Leakage Currents vs. Temperature

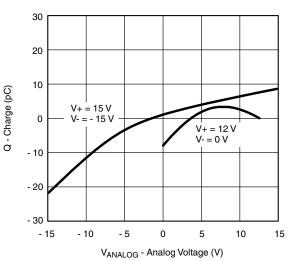
### TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



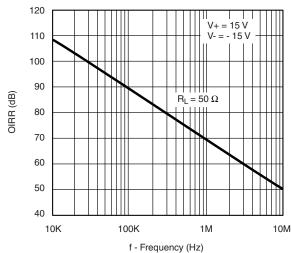
Switching Time vs. Single Supply Voltage



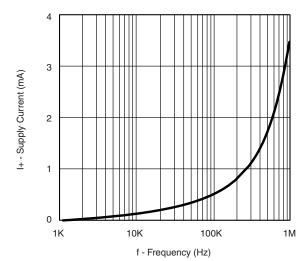
Switching Time vs. Power Supply Voltage



Q<sub>S</sub>, Q<sub>D</sub> - Charge Injection vs. Analog Voltage



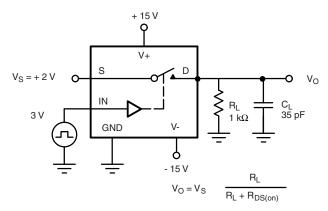
Off Isolation vs. Frequency



**Supply Current vs. Switching Frequency** 



#### **TEST CIRCUITS**



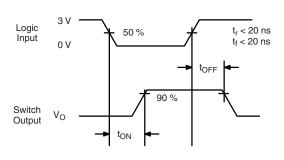


Figure 2. Switching Time

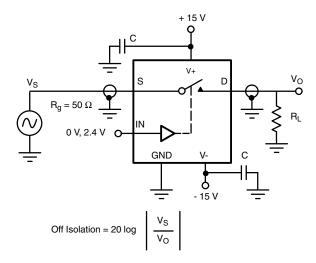


Figure 3. Off Isolation

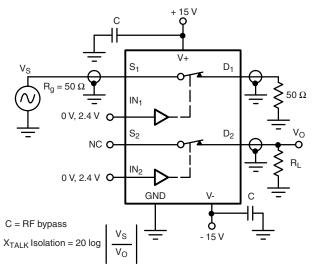
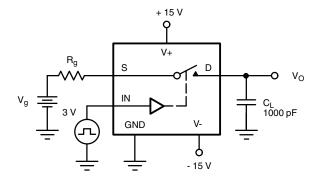
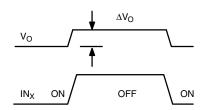


Figure 4. Channel-to-Channel Crosstalk





 $\Delta V_O$  = measured voltage error due to charge injection The charge injection in coulombs is Q = C\_L x  $\Delta V_O$ 

Figure 5. Charge Injection

#### **APPLICATIONS**



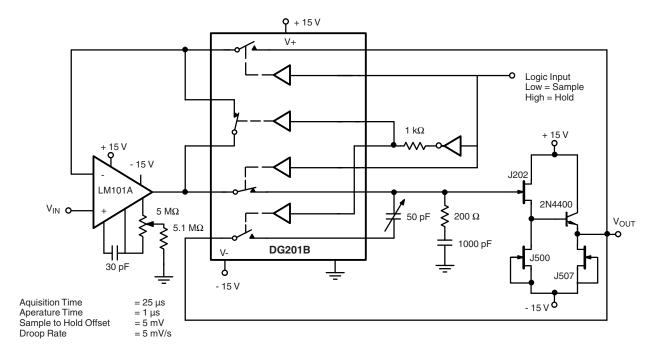


Figure 6. Sample-and-Hold

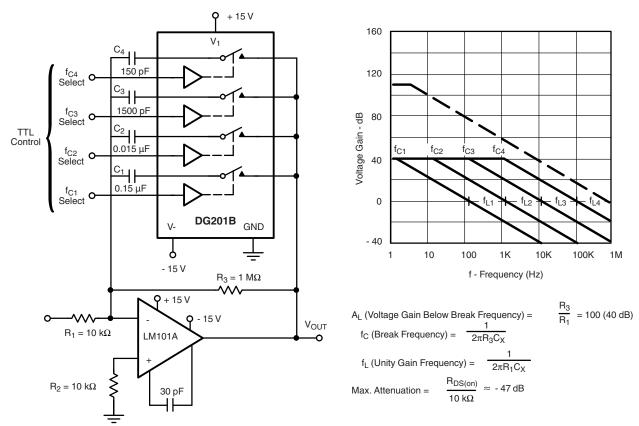


Figure 7. Active Low Pass Filter with Digitally Selected Break Frequency



#### + 15 V 30 pF + 5 V ۷+ $V_{IN1}$ LM101 0 $V_{IN2}$ **Q** + 15 V $R_{\text{F1}}$ 18 $k\Omega$ R<sub>F1</sub> $R_{F1}$ **DG419** $9.9~\mathrm{k}\Omega$ 100 kΩ 0 **DG202B** СН **GND** V-P - 15 V $\begin{array}{c} {\sf R}_{\sf G2} \\ {\sf 100}~\Omega \end{array}$ $R_{G3}$ 100 $\Omega$ Gain 1 (x1) O $R_F + R_G$ Gain 2 (x10) O Gain 3 (x100) O

Figure 8. A Precision Amplifier with Digitally Programable Input and Gains

V-

GND

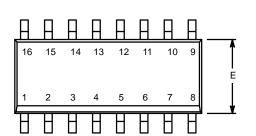
Gain 4 (x1000) o-

Logic High = Switch On

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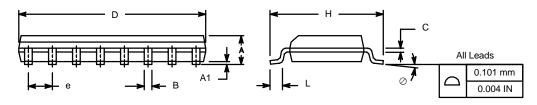
SOIC (NARROW): 16-LEAD
JEDEC Part Number: MS-012



	MILLIMETERS		INC	HES			
Dim	Min	Max	Min	Max			
Α	1.35	1.75	0.053	0.069			
A <sub>1</sub>	0.10	0.20	0.004	0.008			
В	0.38	0.51	0.015	0.020			
С	0.18	0.23	0.007	0.009			
D	9.80	10.00	0.385	0.393			
E	3.80	4.00	0.149	0.157			
е	1.27	0.050	050 BSC				
Н	5.80	6.20	0.228	0.244			
L	0.50	0.93	0.020	0.037			
0	0°	8°	0°	8°			
FCN: S-0	FCN: S-03946—Rev F 09-Jul-01						

ECN: S-03946—Rev. F, 09-Jul-01

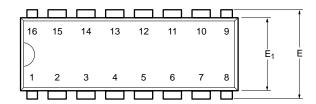
DWG: 5300

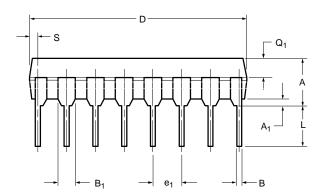


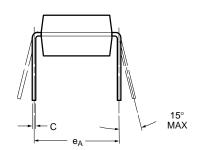
Document Number: 71194 www.vishay.com 02-Jul-01 sww.vishay.com



PDIP: 16-LEAD





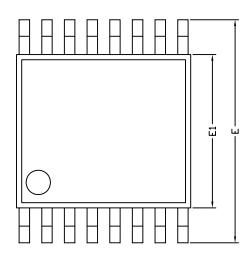


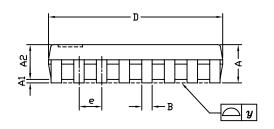
	MILLIMETERS		INC	CHES		
Dim	Min	Max	Min	Max		
Α	3.81	5.08	0.150	0.200		
A <sub>1</sub>	0.38	1.27	0.015	0.050		
В	0.38	0.51	0.015	0.020		
B <sub>1</sub>	0.89	1.65	0.035	0.065		
С	0.20	0.30	0.008	0.012		
D	18.93	21.33	0.745	0.840		
Е	7.62	8.26	0.300	0.325		
E <sub>1</sub>	5.59	7.11	0.220	0.280		
e <sub>1</sub>	2.29	2.79	0.090	0.110		
e <sub>A</sub>	7.37	7.87	0.290	0.310		
L	2.79	3.81	0.110	0.150		
$Q_1$	1.27	2.03	0.050	0.080		
S	0.38	1.52	.015	0.060		
ECN: S-03946—Rev. D, 09-Jul-01 DWG: 5482						

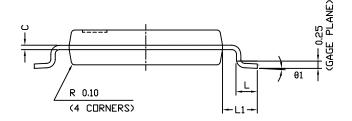
Document Number: 71261 www.vishay.com 06-Jul-01 sum.vishay.com



**TSSOP: 16-LEAD** 







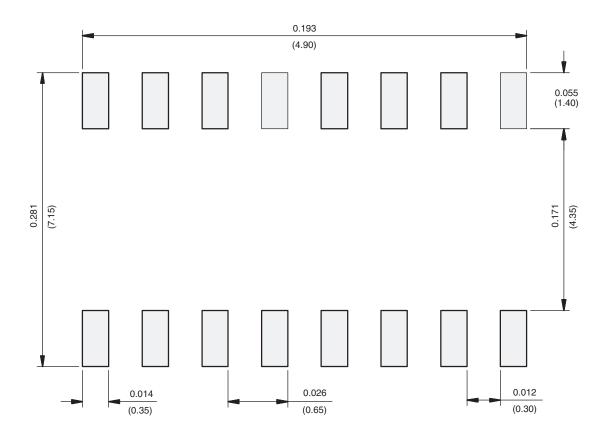
	DIMENSIONS IN MILLIMETERS				
Symbols	Min	Nom	Max		
Α	-	1.10	1.20		
A1	0.05	0.10	0.15		
A2	=	1.00	1.05		
В	0.22	0.28	0.38		
С	=	0.127	-		
D	4.90	5.00	5.10		
E	6.10	6.40	6.70		
E1	4.30	4.40	4.50		
е	-	0.65	-		
L	0.50	0.60	0.70		
L1	0.90	1.00	1.10		
у	=	-	0.10		
θ1	0°	3°	6°		
ECN: S-61920-Rev. D. 23-0	Oct-06				

DWG: 5624

Document Number: 74417 www.vishay.com 23-Oct-06



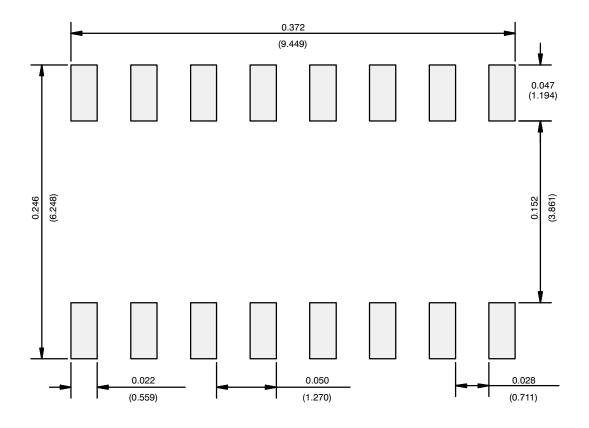
#### **RECOMMENDED MINIMUM PAD FOR TSSOP-16**



Recommended Minimum Pads Dimensions in inches (mm)



#### **RECOMMENDED MINIMUM PADS FOR SO-16**



Recommended Minimum Pads Dimensions in Inches/(mm)

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APPLICATION NOTE

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